



NJX1675PDR2G Information



For Reference Only

Part Number NJX1675PDR2G Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Arrays

Description TRANS NPN/PNP 30V 3A 8SOIC **Package** 8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









NJX1675PDR2G Specifications

Manufacturer Part Number	NJX1675PDR2G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays
Package	8-SOIC (0.154", 3.90mm Width)
Series	-
Transistor Type	NPN, PNP
Current - Collector (Ic) (Max)	3A
Voltage - Collector Emitter Breakdown (Max)	30V
Vce Saturation (Max) @ Ib, Ic	115mV @ 200mA, 2A, 170mV @ 200mA, 2A
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	180 @ 1A, 2V
Power - Max	2W
Frequency - Transition	100MHz, 120MHz
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SOIC
	Report errors?

NJX1675PDR2G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NJX1675PDR2G Payment Methods



















NJX1675PDR2G Shipping Methods













If you have any question about NJX1675PDR2G, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com